

# Automotive-grade, 1200 V, 50 A SCR: TN5050H-12WY AC/DC converter applications



**This 1200 V, 50 A automotive-grade thyristor makes AC/DC converters safe by limiting the inrush current and providing insulation against AC line overvoltages**

Available in a TO-247, high power package, the TN5050H-12WY automotive-grade SCR is suitable for automotive / stationary battery chargers, renewable energy generators, uninterruptible power supplies, solid state relays, welding equipment and motor drive applications. The TN5050H-12WY offers superior performance in surge current handling (ITSM = 200 A at 10ms), thermal cooling capabilities ( $R_{th(j-c)} = 0.3 \text{ }^{\circ}\text{C/W}$ ) and high surge voltage withstanding capability (VDSM/VRSM = 1300 V).

## KEY FEATURES

- On-state RMS current: 50 A
- Blocking voltage: 1200 V
- High commutation: 200 A/ $\mu\text{s}$
- High off-state immunity: 1000 V/ $\mu\text{s}$
- Gate trigger current: 50 mA
- AEC-Q101 compliant
- ECOPACK<sup>®</sup>2 compliant

## KEY BENEFITS

- Automotive grade: reliability, quality and AEC-Q101 compliance
- Reduce BOM: extra power device no longer needed in the rectifier bridge
- Same efficiency/dissipation and cooling size as diode bridge
- High PCB creepage distance above 4mm
- Control peak current at charger power up

## TARGETED APPLICATIONS

- EV/HEV (on board, off board battery chargers)
- Industrial battery chargers
- Renewable energy inverters
- Solid state relays
- Uninterruptible power supplies (bypass)
- Motor drive (inrush current limiter, soft start)
- Industrial welding system





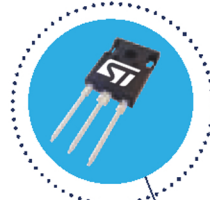
**TN5050H-12WY IN BRIEF**



**Automotive grade**

**Automotive grade:**  
Enhance reliability and quality, AEC-Q101 compliance  
Enhance commercial services (priority and stocks)

**Reduced BOM:**  
No more extra power device in the bridge



**TO 247  
UL94-V0**



**EFFICIENCY:**  
Same efficiency and cooling size as diode bridge

**ROBUST DESIGN:**  
Inrush current limiter  
voltage withstanding capability

**TN5050H-12WY PRODUCT TABLE**

Part number	Package	Triggering gate current (IGT)	Repetitive peak off-state voltage ( $V_{DRM}$ and $V_{BRM}$ )	Junction temperature ( $T_j$ )	RMS on-state current $I_{T(RMS)}$	Peak on-state voltage ( $V_{TM}$ )	Maximum leakage current (IDRM and IRRM) (@ $T_j = 25^\circ\text{C}$ )	Non-repetitive surge-peak on-state current (@ $t_p = 10\text{ ms}$ ) $I_{TSM}$	Critical rate of rise of off-state voltage (dV/dt)	Junction-to-case thermal resistance $R_{th(j-c)}$
		max (mA)	max (V)	max ( $^\circ\text{C}$ )	(A)	max (V)	max ( $\mu\text{A}$ )	(A)	min (V/ $\mu\text{s}$ )	( $^\circ\text{C}/\text{W}$ )
<b>Automotive-grade AECQ-101-compliant</b>										
<b>TN5050H-12WY</b>	T0247	50	1200	150	50	1.55	5	580	1000	0.3

Application note AN4606 with additional information about the inrush current limiter function in the thyristor-triac is available on [st.com](http://st.com)